

*Micro-optical switches for future telecommunication  
payloads :  
achievements of the SAT 'N LIGHT Project*

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1) **serealo**  
Microtechnology Ltd.

3) **Contraves** | Space

2)  **ALCATEL ALENIA SPACE**  
An Alcatel/Finmeccanica company

4)  **imt**

## *Micro-optical switches for future telecommunication payloads*

- I. Sat ´n Light
- II. Performance of serecalo ´s 4x4 *cascaded* optical MEMS switch
- III. Performance of the 8x8 *monolithic* optical MEMS switch
- IV. Conclusion

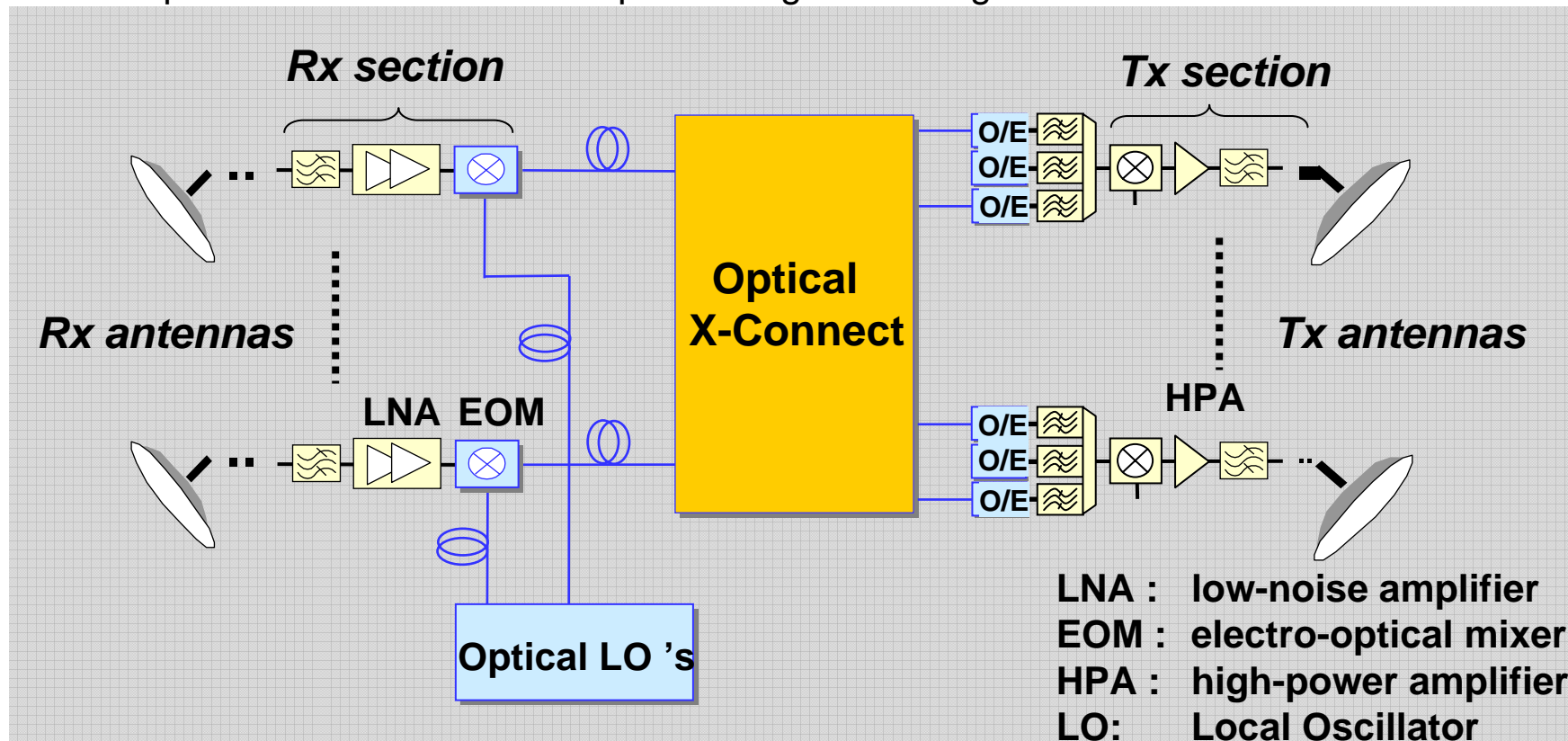
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- Activity Title : *Optical Handling of Microwave and Digital Signals*
- Nickname : *SAT 'N LIGHT*
- Funding : ESTEC contract n°15695/01/NL/ND (Technology Research Programme)
- Objectives
  - Study and demonstrate the use of optical techniques and technologies for all possible applications of electronic signals of any form on-board of satellite payloads
  - Assess the potentials of optical technologies for such applications, by contributing to new payload designs, designing payload functional blocks based on all-optical or hybrid optoelectronic modules, and demonstrating their performance through breadboarding of a selected number of modules / systems

## Satellite telecom payload with flexible beam-to-beam connectivity

- optical generation & distribution of high-frequency LO's (> 10 GHz)
- optical frequency mixing and down-conversion, e.g. from Ka (30GHz) to C (4GHz)
- optical cross-connection of  $\mu$ -wave signals through MOEMS switches

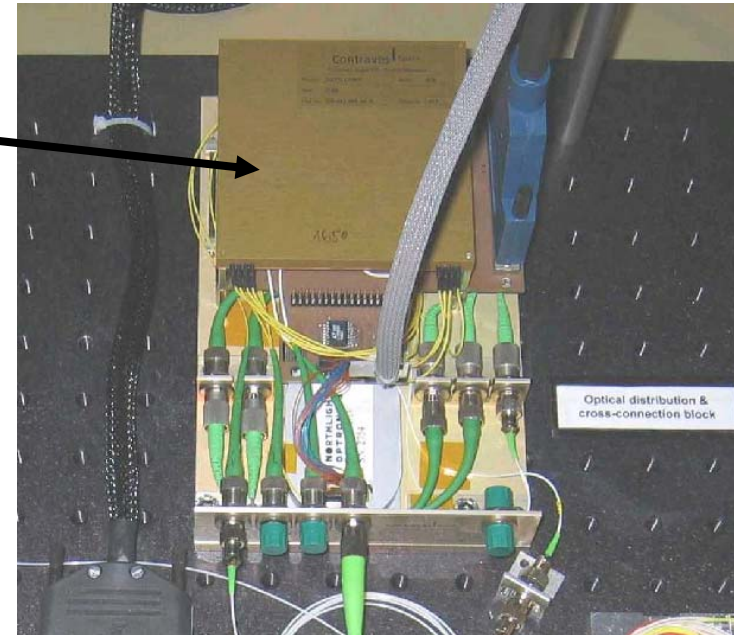


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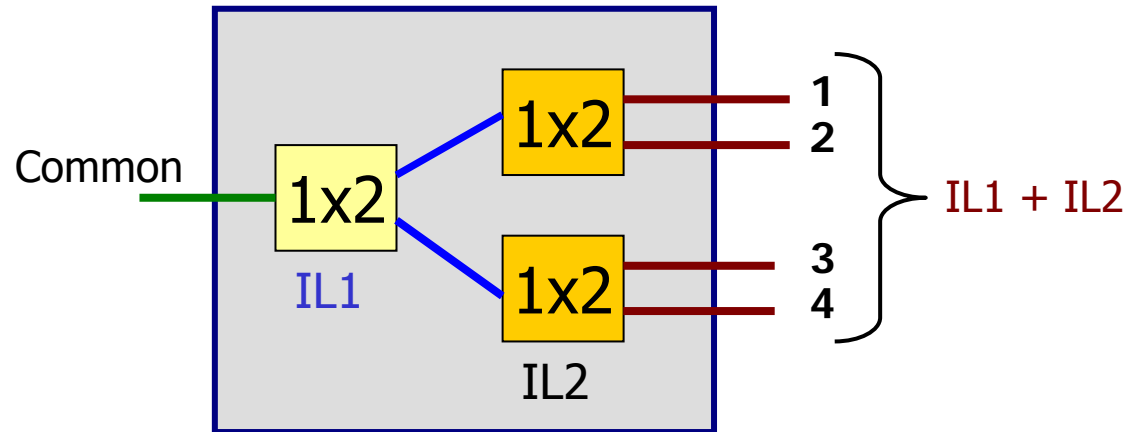
## *Why MEMS based high-performance optical cross connect ???*

Sercalo ´s MEMS based optical 4x4 latching switch  
Integrated by CONTRAVES Space AG



- Solid state reliability
- NO observable RF crosstalk ( $< -70$  dB) whatever the OXC configuration
- NO degradation of the linearity performance
- NO observable increase of phase noise of microwave signals

## 1x4 Cascading principle

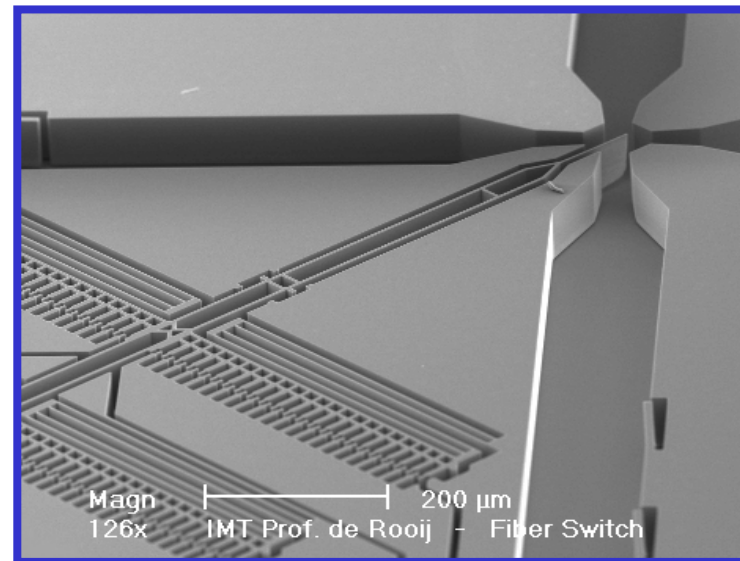


## Advantages

- ✓ Low insertion loss at small port count
- ✓ Flexibility in design
- ✓ 6 years market proven

## Disadvantages

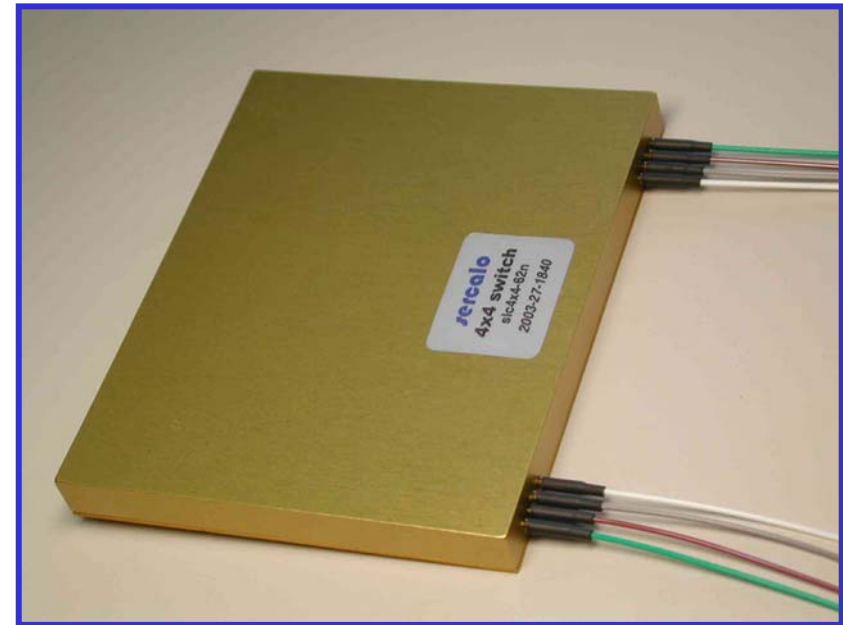
- ✓ Large size due to fiber bends
- ✓ Very labor intensive assembly
- ✓ Almost impossible assembly at large port count
- ✓ Reliability decreases with complexity





## *Performance of sercalo´s 4x4 latching MEMS switch*

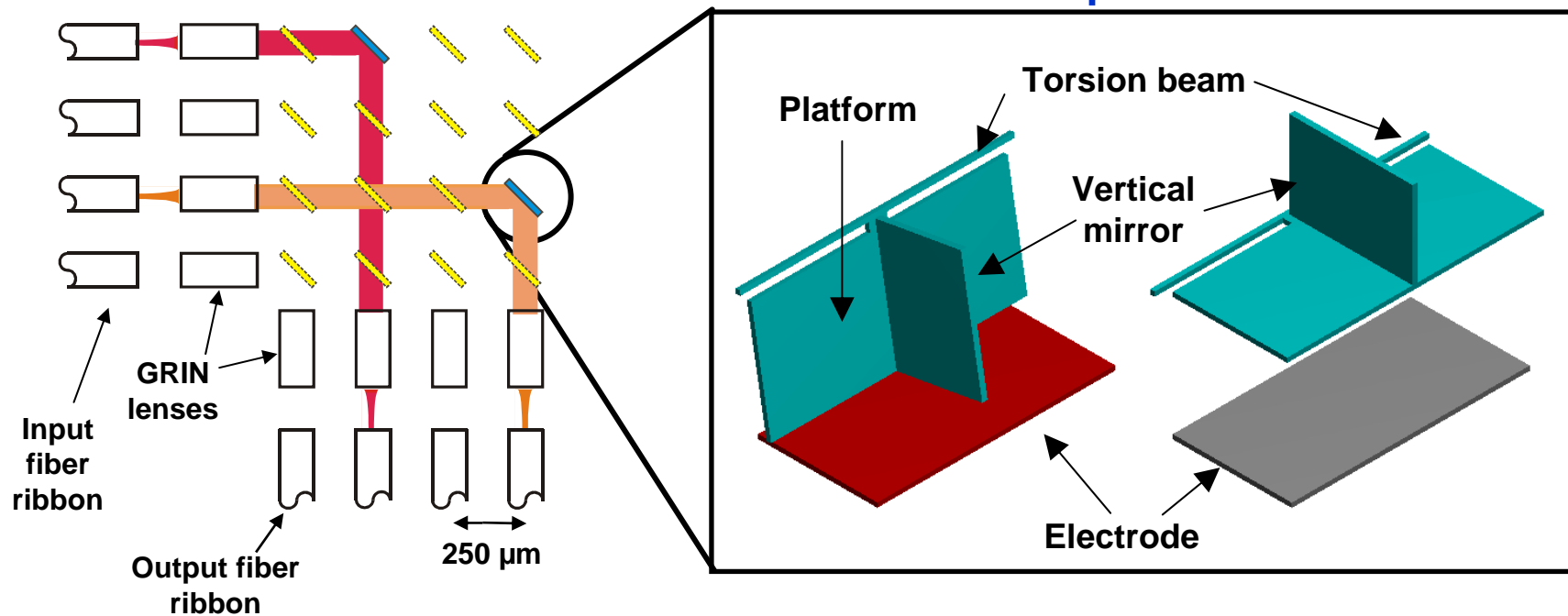
- **Insertion Loss (IL):** < 1.65 dB
- **Cross Talk (CT):** > 69 dB
- **Polarization Dep. loss (PDL):** < 0.08 dB
- **Return Loss (RL):** > 52 dB
- **Power during switching:** 75mW
- **Power during operation:** 1mW
- **Switching speed:** < 1ms
- **Qualification:** Telcordia 1221
- **1x2 in Space Radiation Environment:** Co60  $\gamma$ -ray radiation source at a dose rate of 330 rad/h to total dose up to 22.5 krad  
(IEEE Transactions on nuclear science Vol.52,No.4, by G. Quadri, French Space Agency CNES)



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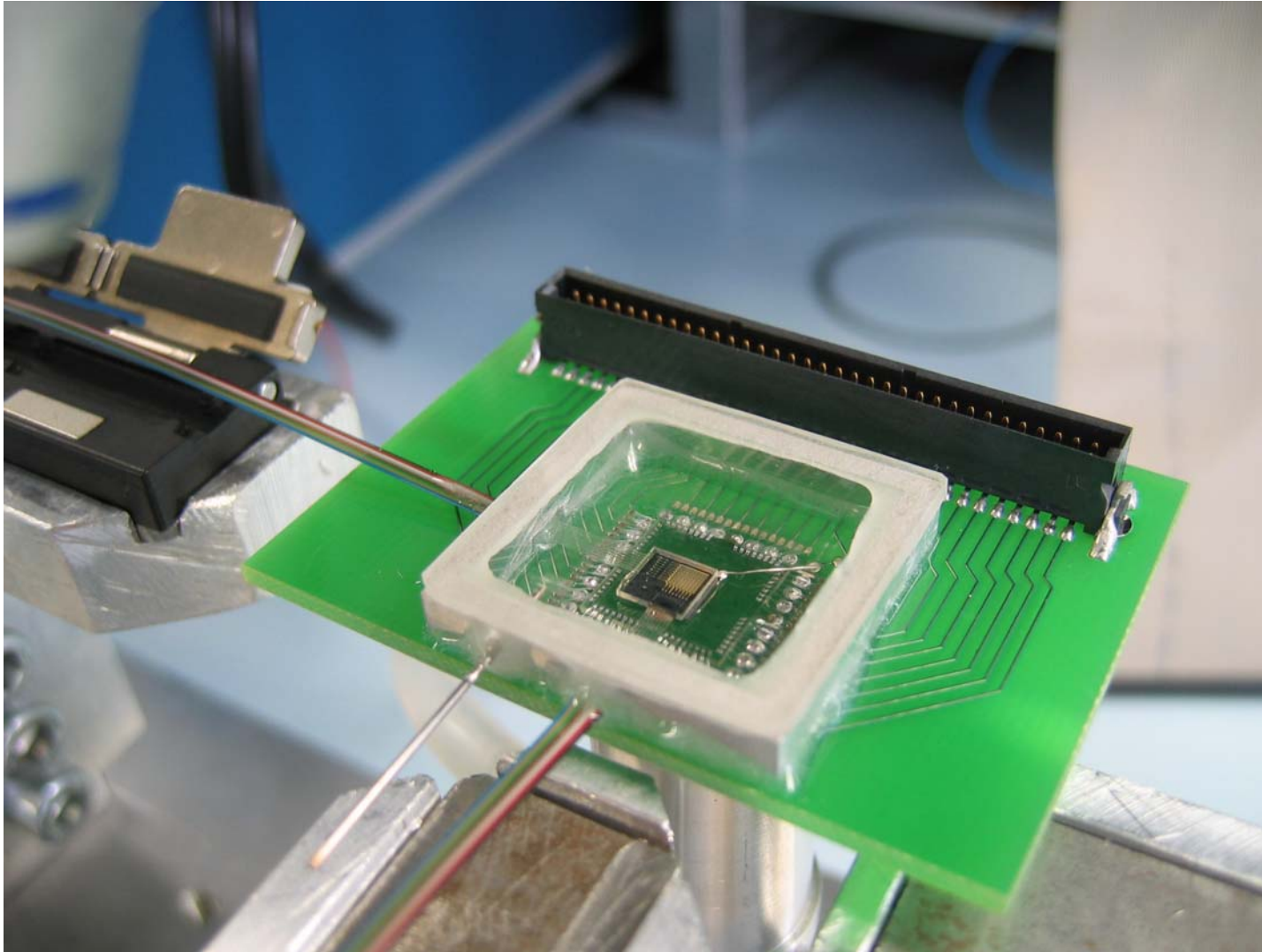
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## 8x8 Monolytic Optical Cross Connect

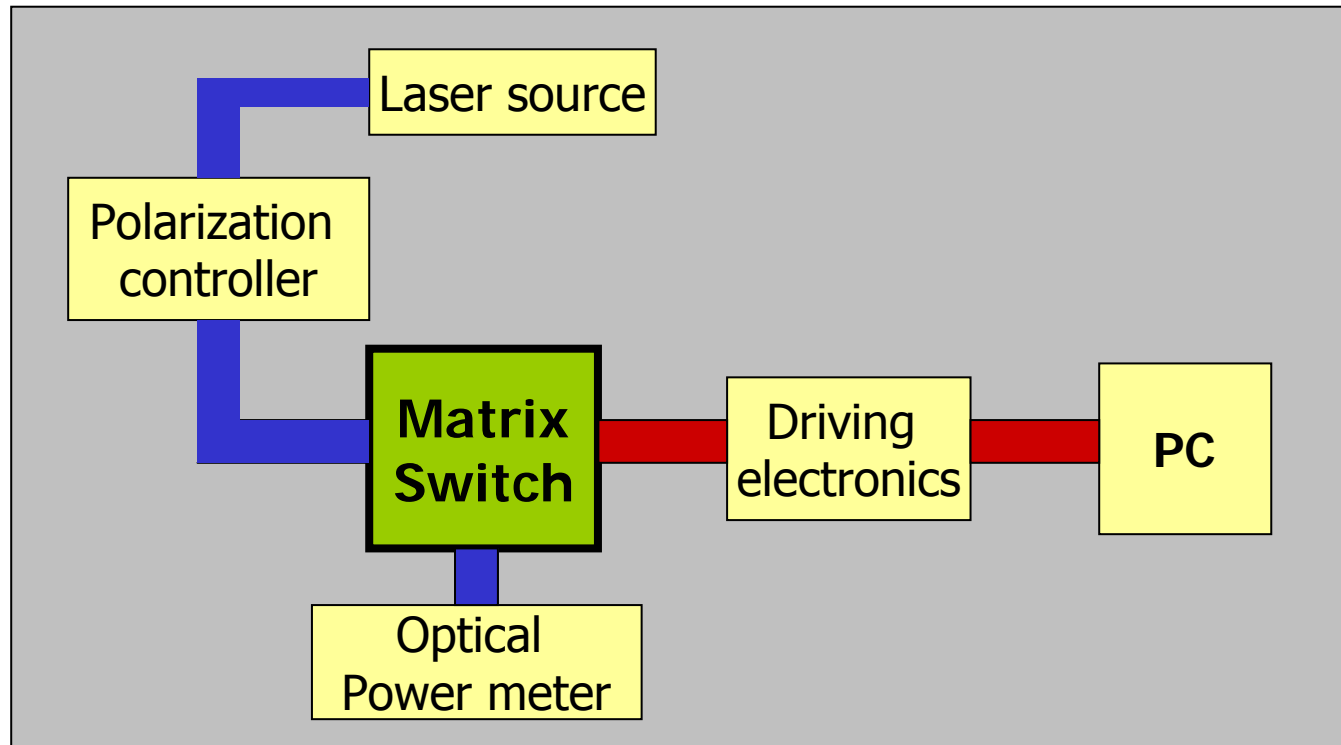


- Pitch of mirrors = pitch of fiber ribbons (250 μm)
- GRIN lenses for coupling efficiency at small foot print
- Flip mirrors with torsion hinges and bottom electrodes
- Mirror chip: silicon bulk micromachining (DRIE)
- Electrodes on separate chip

## *8x8 Monolytic Optical Cross Connect*



## *Optical Performance*



### Equipment:

Laser source:

Profile LDS 1550 at 1550nm wavelength

Laser power meter:

Agilent 8164A with eight 81634A Power sensors

Polarization Controller:

Agilent 11896A

*Optical Performance*

Insertion Loss [dB]

Best Value: 4.5 dB  
Worst Value: 14dB

	Out 1	Out 2	Out 3	Out 4	Out 5	Out 6	Out 7	Out 8
In 1	N/A	6.5	5.7	6.3	7.5	7.9	8.9	10.9
In 2	4.5	6.5	7.9	8.8	9.6	10.4	9.8	13.5
In 3	7.2	9.1	10.4	9.9	11.2	10.7	13.3	13.3
In 4	6.5	8.0	8.6	9.3	10.1	10.0	12.4	12.0
In 5	7.5	9.8	8.9	9.5	11.1	10.2	11.7	12.4
In 6	9.7	10.7	10.3	10.2	11.2	11.1	N/A	N/A
In 7	12.7	13.9	14.1	12.8	12.6	13.4	N/A	N/A
In 8	10.1	11.1	12.0	N/A	N/A	N/A	N/A	N/A

Polarisation depending Loss: 0.5dB

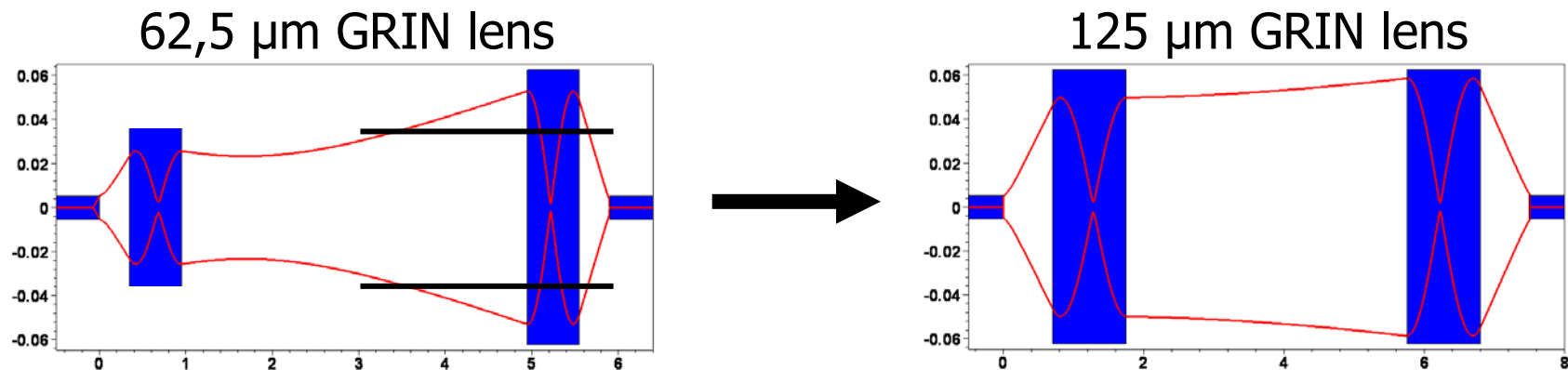
Actuation voltage : 260V

Spacer: 150µm

## IMPROVING HIGH INSERTION LOSS

- refining the sputter process (better mirror reflectivity)
- new GRIN lenses

### Simulation based on ABCD Matrix



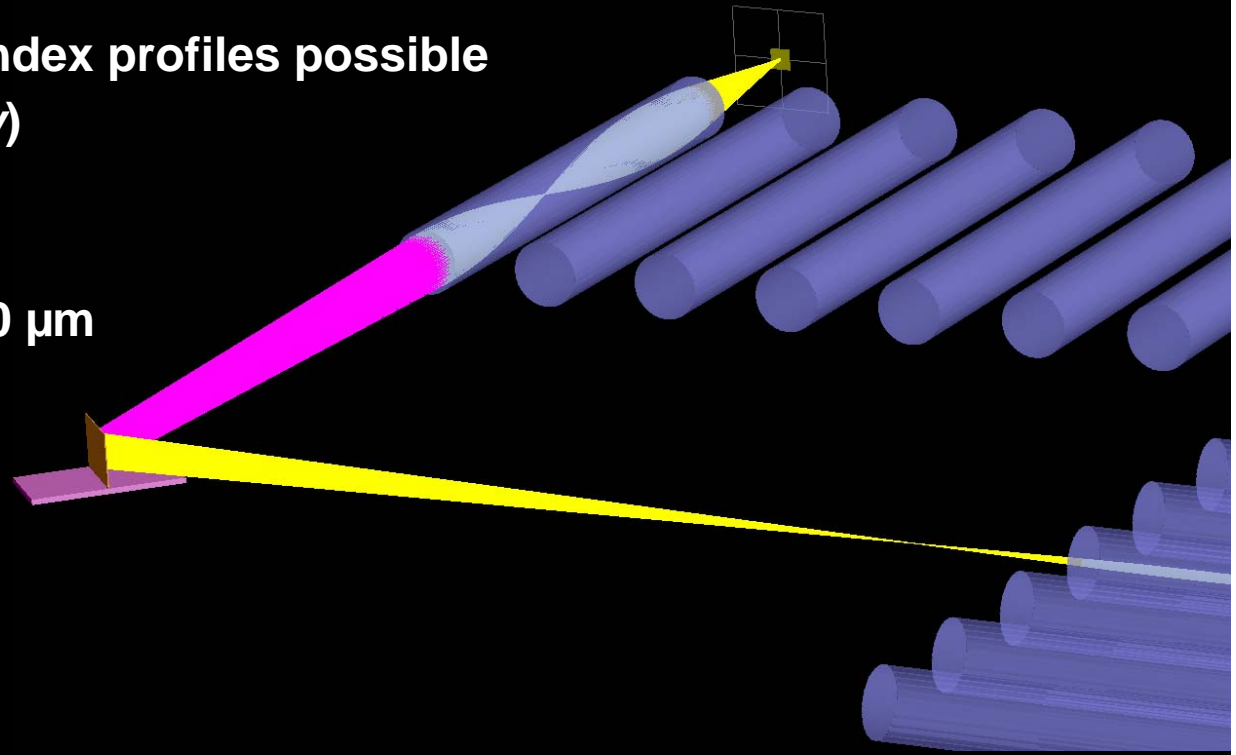
- NO Diffraction
- NO Fresnel loss
- NO Loss origin from too big beam diameter

} in simulation included

## Optical Simulation - Fiber Switch 8x8



- FRED from *Photon Engineering*
  - Raytracing
  - Gaussian beamlets
  - Diffraction effects
- Arbitrary 3D refractive index profiles possible
  - GRIN lenses:  $n(x,y)$
- $\mu$ -GRIN lenses:
  - $\varnothing_{\text{MMF}} = 125 \mu\text{m}$
  - $\varnothing_{\text{core}} = 66 \text{ and } 110 \mu\text{m}$
  - Length varied
- Index matching fluid

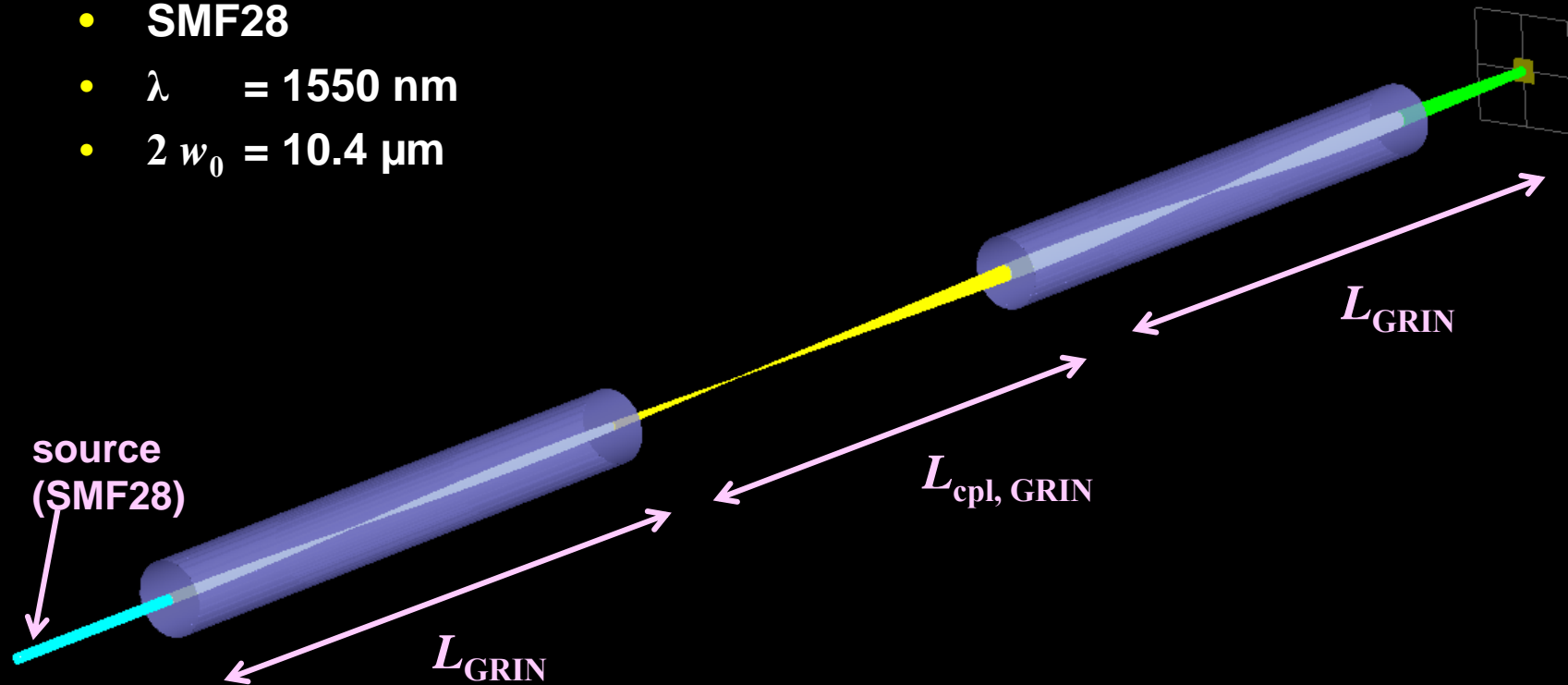




## Insertion Loss 62,5 $\mu\text{m}$ vs 110 $\mu\text{m}$ GRIN lens



- Simple line-up of two  $\mu\text{-GRIN}$  lenses:
  - Diameter = 125  $\mu\text{m}$
  - Length and distance are varied
- Source
  - SMF28
  - $\lambda = 1550 \text{ nm}$
  - $2 w_0 = 10.4 \mu\text{m}$





# Insertion Loss 62,5μm vs 110μm GRIN lens

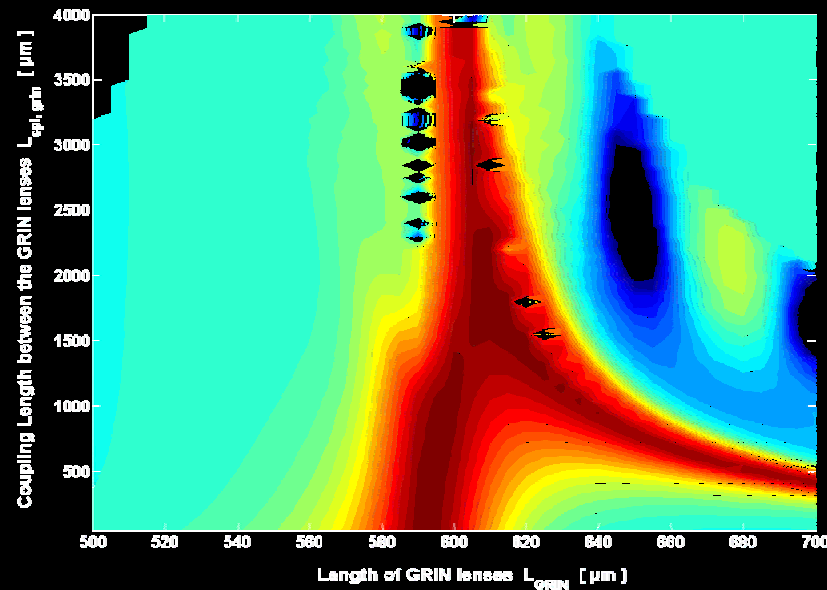
Line-up of μ-GRIN lenses

- $D_{smf,grin} = 350 \mu m$
- $\varnothing_{GRIN} = 125 \mu m$

$$n_{core}(r) = \sqrt{n_0^2 (1 - \alpha^2 r^2)}$$

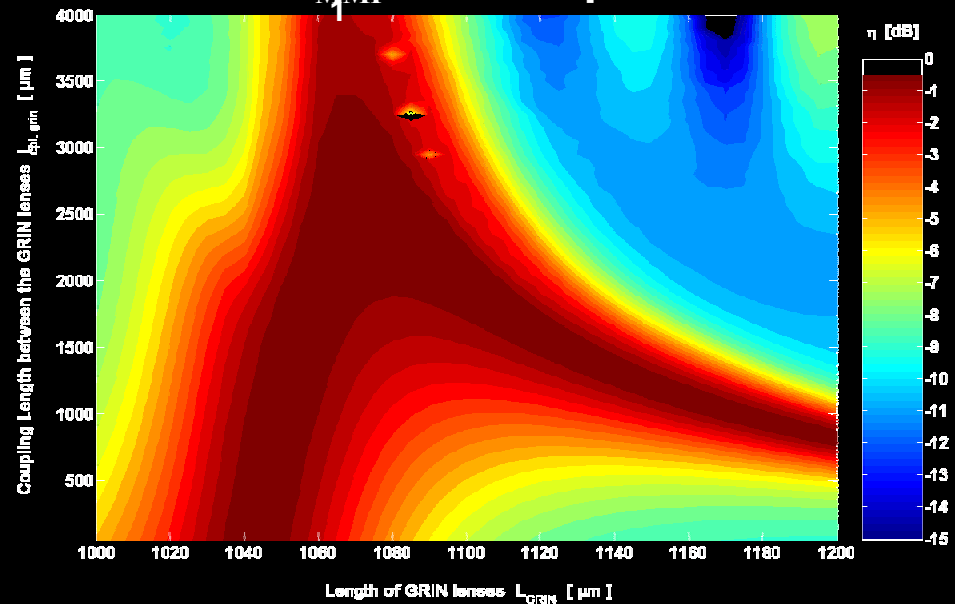
$\varnothing_{core} = 66 \mu m$

$\alpha_{MMF} = 0.006 \mu m^{-1}$

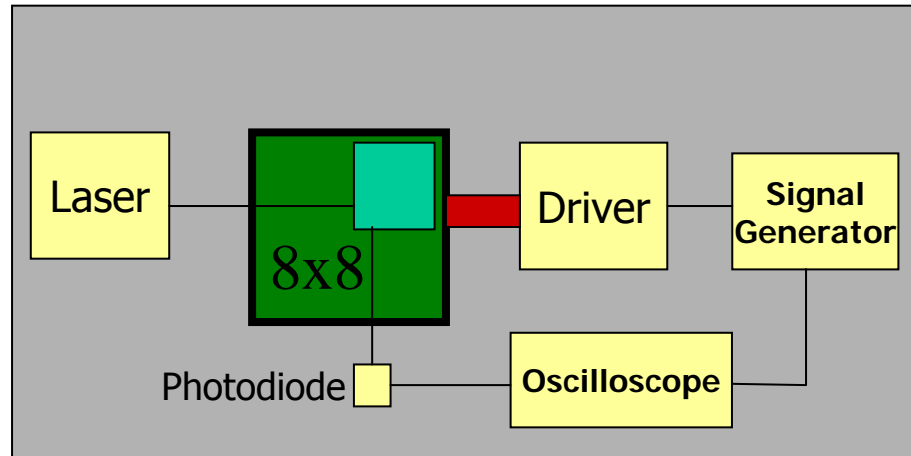


$\varnothing_{core} = 110 \mu m$

$\alpha_{MMF} = 0.0036 \mu m^{-1}$

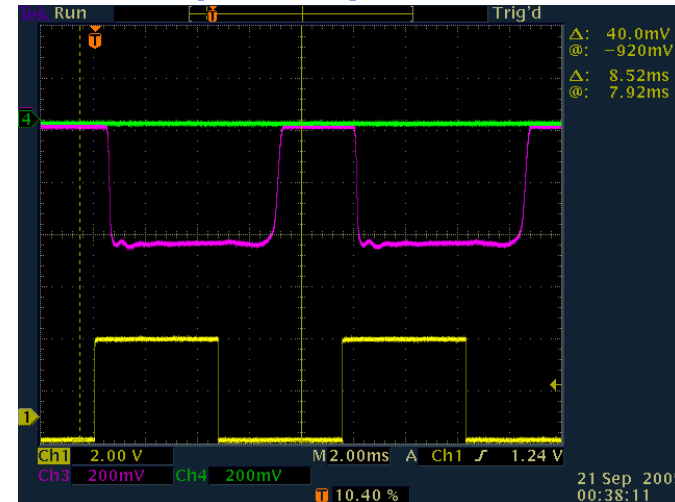


## Switching speed



- Actuation Voltage: 330V
- Insertion Loss: 8.7dB
- Switching time down: ~1ms@100Hz
- Switching time up: ~2ms@100Hz

## Frequency: 100 Hz

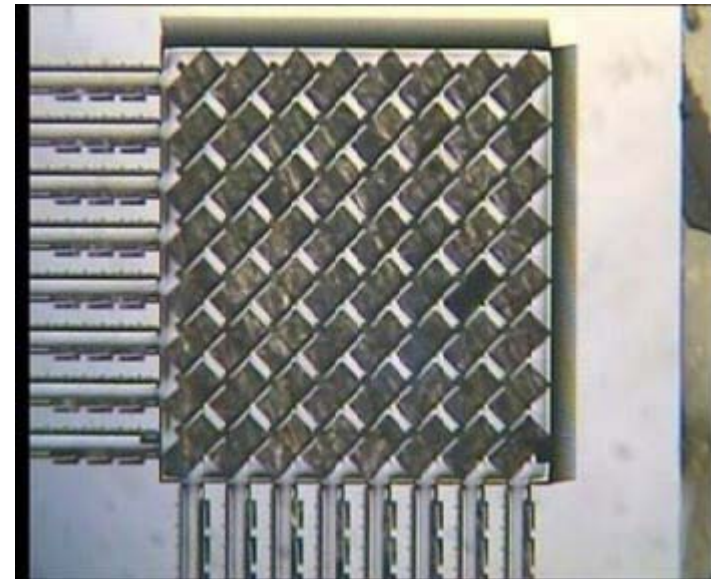


## Frequency: 200 Hz



## *Mechanical Reliability Test*

- Actuation Voltage: 330V
- Tilting Angle: 90°
- Switching frequency: 10 Hz



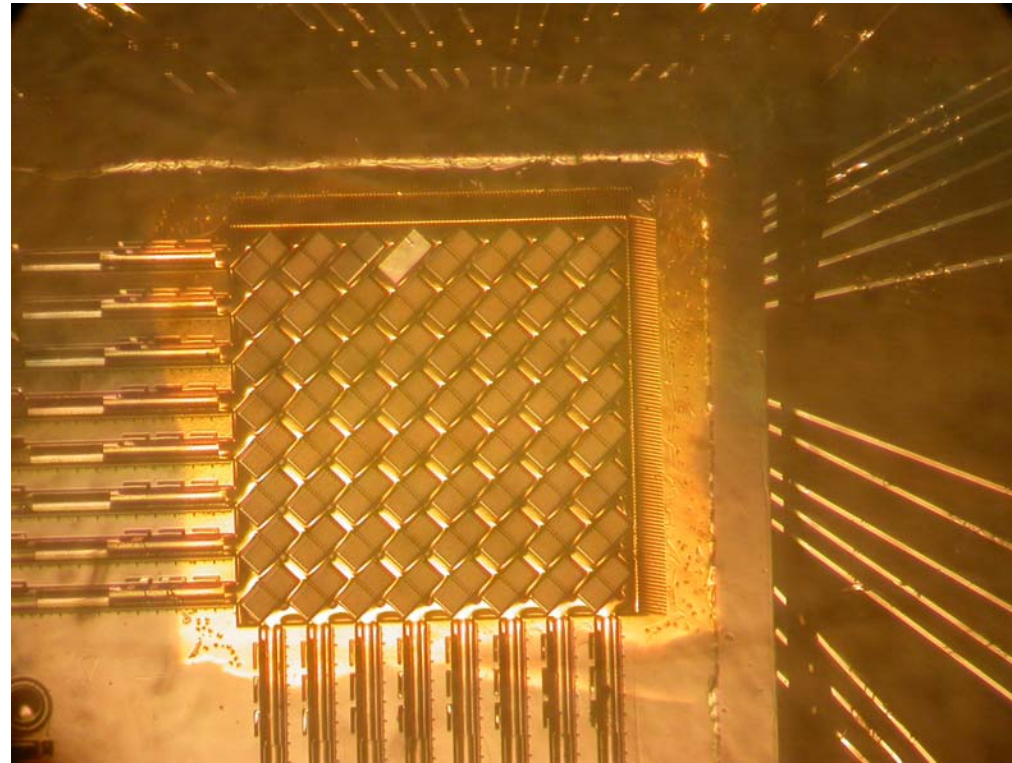
9.0 Million switching cycles  
NO breakage or deformation  
by tilting the mirror 90°

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### *Conclusion*

- ✓ *SAT´n Light shows the advantages of using MEMS based optical switches in RF telecom payload*
- ✓ *I presented the exceptional performance of sercalo´s **cascaded** 4x4 optical MEMS based switch with solid state reliability and IL below 1.7dB*
- ✓ *A new **monolytic** MEMS based OXC showed promising starting values like switching speed of 1-2ms and 9 million switching cycles without noticable decrease of performance*
- ✓ *Future improvements as refining the chip design and usage of bigger GRIN lenses will lead to even better performances in Insertion Loss and homogeneity of the switch*



***Thank You !!!***

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